

#### **Features**

- Fast Switching
- · Improved dv/dt Capability
- · Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free. "Green" Device
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## N-CHANNEL MOSFET

## **Maximum Ratings**

• Operating Junction Temperature Range : -55°C to +175°C

• Storage Temperature Range : -55°C to +175°C

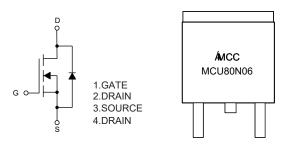
• Thermal Resistance : 1.76°C/W Junction to Case

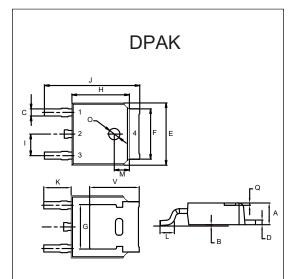
Parameter		Symbol	Value	
Drain-source Voltage		$V_{DS}$	60V	
Gate-source Volltage		$V_{GS}$	±20V	
Drain Current	T <sub>C</sub> =25°C	ı	80A	
	T <sub>C</sub> =100°C	I <sub>D</sub>	56A	
Pulsed Drain Current		I <sub>DM</sub>	240A	
Power Dissipation		$P_{D}$	68W	
Single Pulsed Avalanche Energy <sup>(1)</sup>		E <sub>AS</sub>	225mJ	

Note: 1. Eas Condition: Tj=25  $^{\circ}\text{C}$  ,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$ 

# nJ

## **Internal Structure and Marking Code**





	DIMENSIONS				
INCHES		MM			
DIM	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Η	0.236	0.244	6.00	6.20	
_	0.086	0.094	2.18	2.39	
7	0.386	0.409	9.80	10.40	
K	0.1	14	2.9	90	TYP.
L	0.055	0.067	1.40	1.70	
М	0.0	63	1.0	60	TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	V 0.211		5.35		TYP.

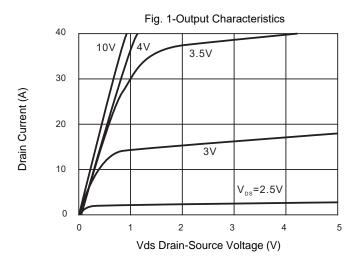


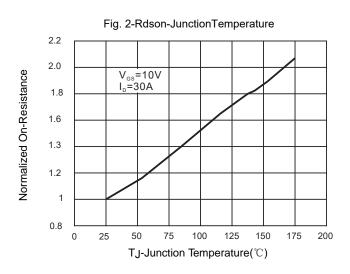
## **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

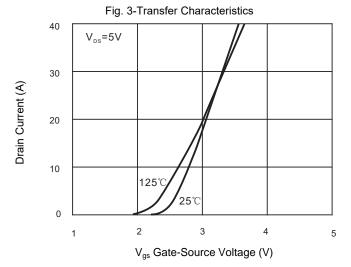
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			•
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics	<u>.</u>		•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.2	1.7	2	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A		5.5	7.5	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A		6.9	9.5	mΩ
Forward Transconductance	<b>g</b> FS	$V_{DS}=5V,I_{D}=30A$	30	-	-	S
Dynamic Characteristics	<u>.</u>		•			
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V,	-	1990	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, F=1.0MHz	-	470	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0Winz	-	14	-	PF
Switching Characteristics	·		•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	16	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_D$ =2A, $R_L$ =1 $\Omega$	-	8	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =3 $\Omega$	-	45	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	33	-	nS
Total Gate Charge	Qg	V 20VI 20A	-	31	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =30V, $I_{D}$ =20A, $V_{GS}$ =10V	-	6	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	$V_{GS}=0V,I_{S}=30A$	-	-	1.2	V
Diode Forward Current	Is		-	-	80	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25℃, IF =30A	-	35		nS
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 100A/µs	-	47		nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

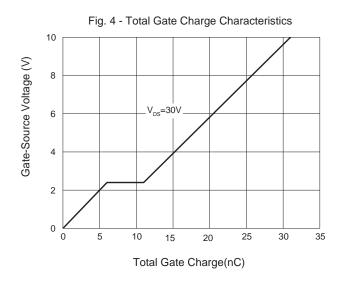


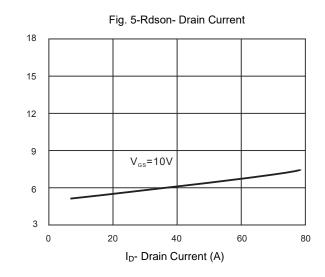
#### **Curve Characteristics**



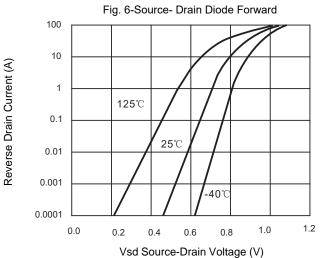






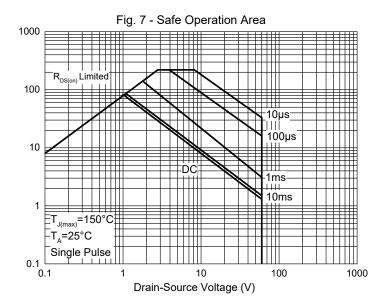


Rdson On-Resistance(m $\Omega$ )





### **Curve Characteristics**





#### **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel:2.5Kpcs/Reel

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